

# «*Software design for a PIN detector of ionizing radiation*»

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- Science advisor: RNDr. Ivana Krausová, Ph.D., NPI of the CAS



1. Aim of diploma thesis
2. Microtron MT25
3. Ionizing Radiation Detector
4. PIN photodiode
5. KID board
6. Collecting data
7. Processor ARM Cortex M0+ (STM32L053 Discovery board)
8. Tasks of diploma thesis
9. My first results
10. Conclusion

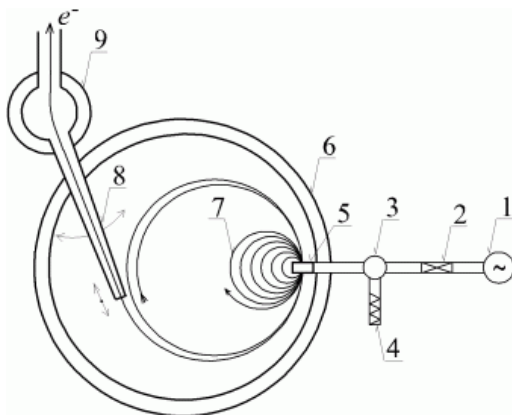


The aim of diploma thesis is to create software for a new type of spectrometric detector of ionizing radiation that work as a **personal dosimeter** for aircraft crew members.

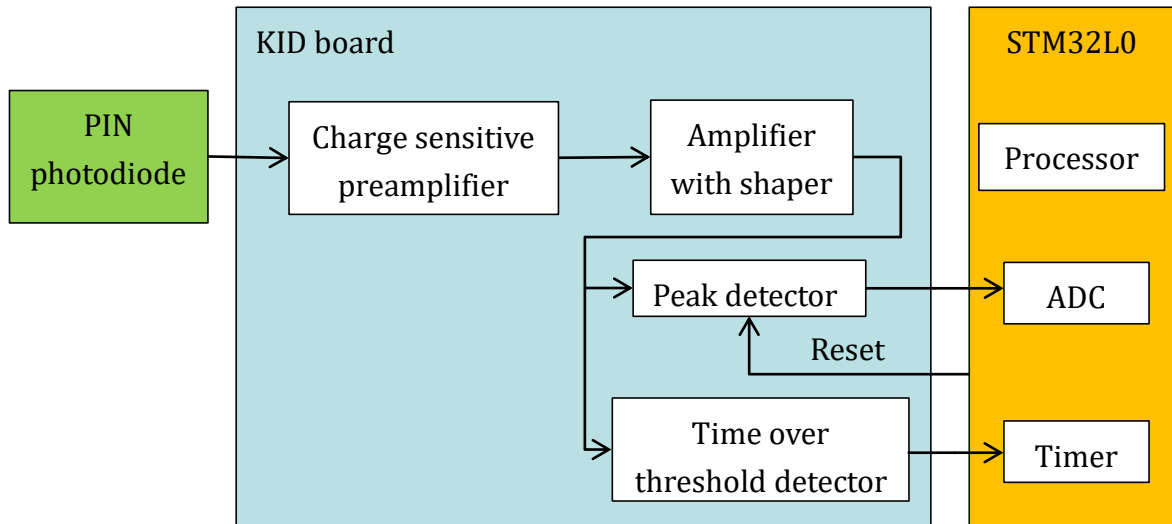
Detector test will be made in the **Microtron laboratory**.

Ultra-low-power **ARM Cortex-M0+** processor is used for data acquisition and processing.

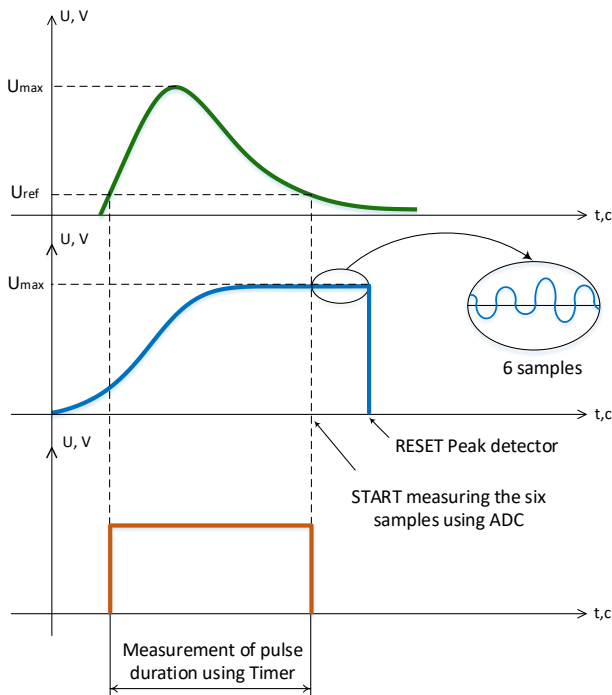




Schematic layout of the MT25 microtron: 1 – magnetron, 2 – phase shifter, 3 – circulator,  
 4 – water load, 5 – accelerating cavity,  
 6 – main magnet (vacuum chamber), 7 – electron trajectories, 8 – adjustable beam  
 extractor, 9 – first deflector



# Ionizing Radiation Detector



1. Voltage pulse  
(charged particle)

2. Positive Peak  
Detector  
(extremum of the  
voltage signal  
measurement)

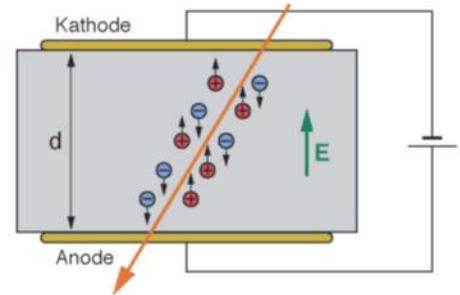
3. Time Over  
Threshold Detector  
(pulse duration  
measurement)



## Advantages of the developed detector:

- ✓ Low-power mode
- ✓ Availability of false signals filtration
- ✓ Orientation on aircraft (continuous measurement)
- ✓ Open sources (all schemes, the method of measurement and microcontroller program are available in the public domain)
- ✓ Universality (it is possible to change the measurement method)

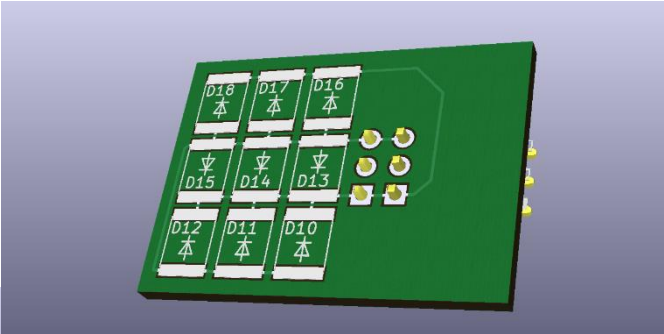
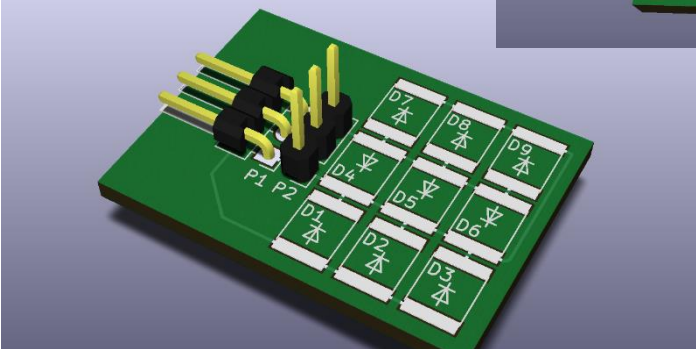
PIN-photodiode consists of p-type, n-type Si semiconductors and intrinsic conductivity portion disposed therebetween.



PIN photodiode detects individual particle of radiation (gamma or charge particle). When a particle strikes a depletion region created by reverse bias on the photodiode, it produces a small amount of charge in proportion to the photon's energy.



# PIN photodiode





TEMD5080X01

## FEATURES

S2744-09

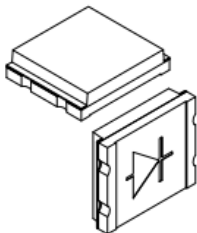
Sensitive area:  $7.7 \text{ mm}^2$

Depletion layer thickness: 0.4 mm

Reverse voltage (max):  $V_R = 25 \text{ V}$

Spectral response range:

350 to 1100 nm



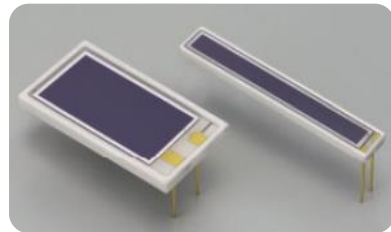
Sensitive area :  $200 \text{ mm}^2$

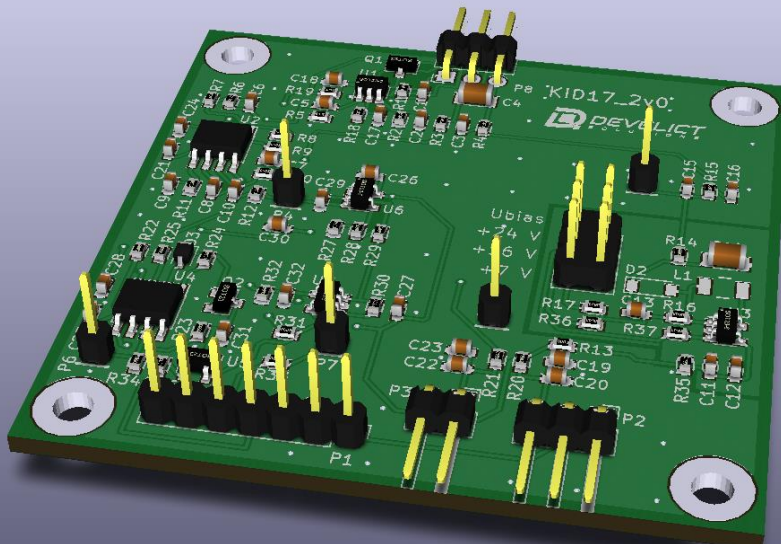
Depletion layer thickness: 0.3 mm

Reverse voltage (max):  $V_R = 100 \text{ V}$

Spectral response range :

340 to 1100 nm

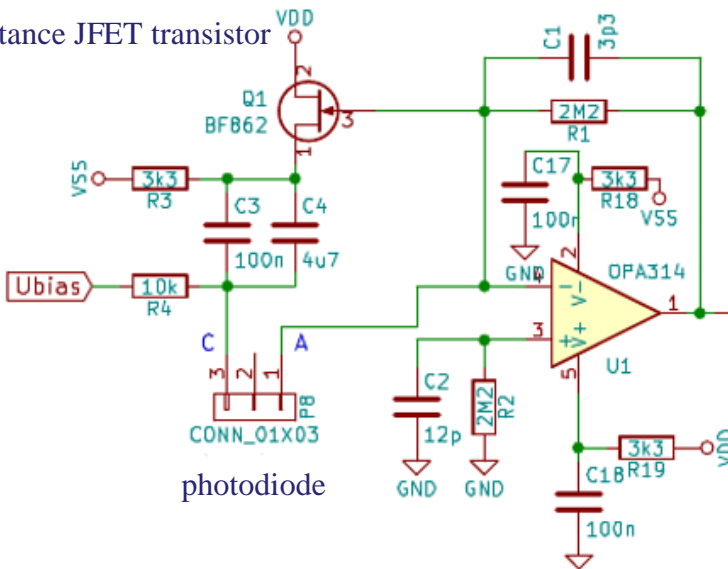






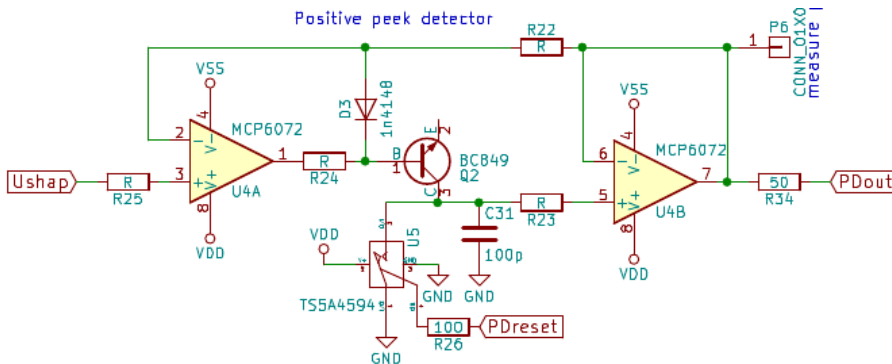
low noise and low capacitance JFET transistor

charge sensitive preamplifier

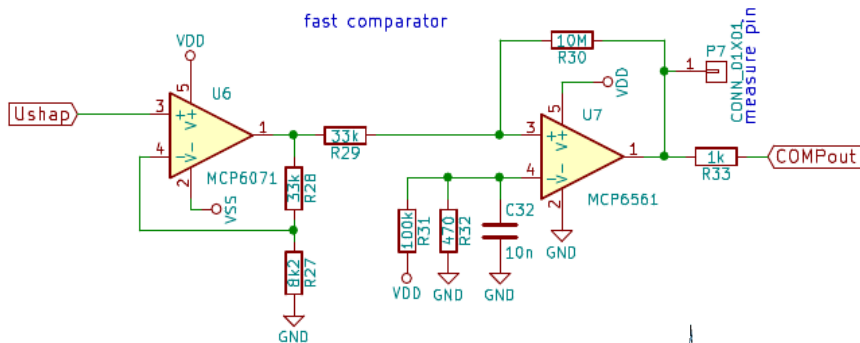


photodiode

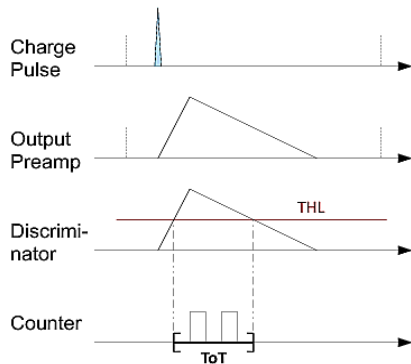
# KID board: Positive peak detector



- Peak detectors capture the extremum of the voltage signal at its input.
- Output voltage is directly proportional to the energy deposited in detection diode.

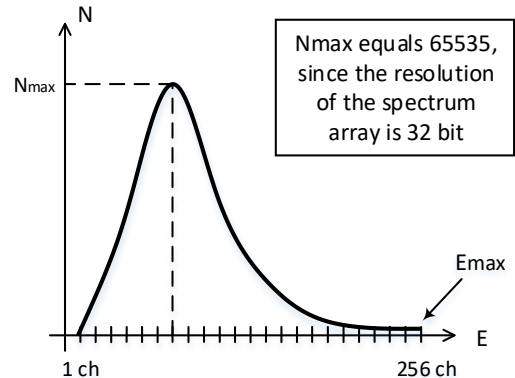


- The time-over-threshold is the number of clock counts in the time interval of the pulse above the threshold.
- The time interval is proportional to the energy deposited in detection diode.



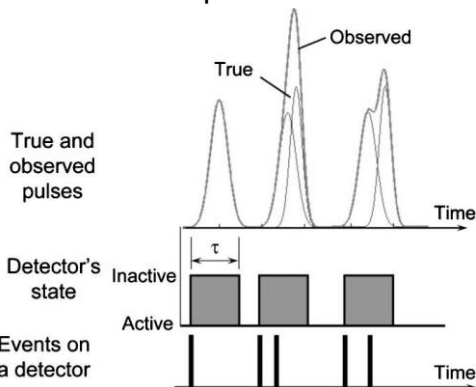
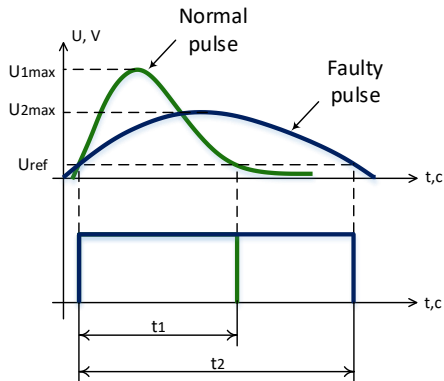


- Detection system feeds microprocessor by signals proportional deposited energy in Si photodiode.
- Processor has to store the data as energy spectrum. Spectrum has 256 channels in which is recorded the number of events (detected particles) in the given energy range.
- After calibration, the data will be converted to dose equivalent.



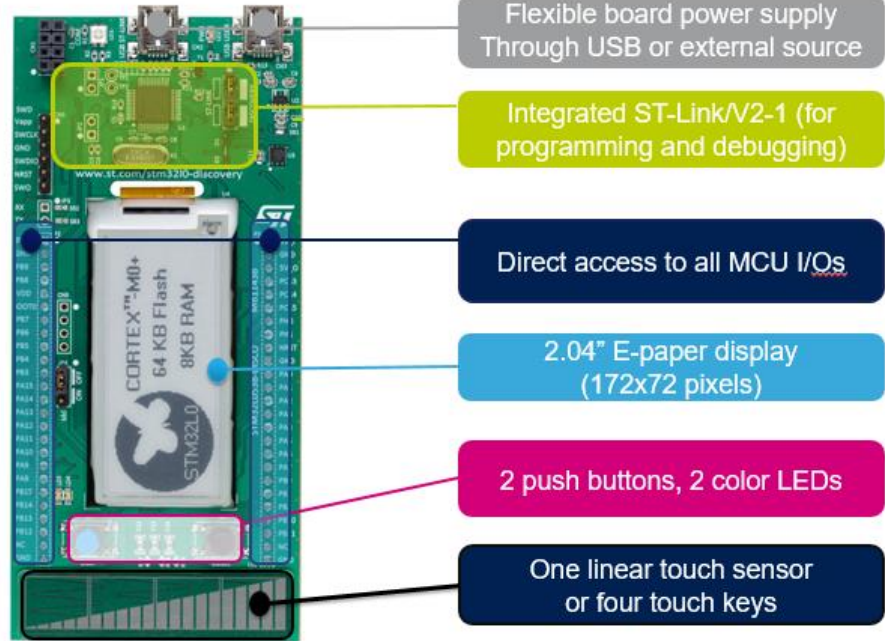


- After loading inputs we can compare the two detectors (peek detectors and time over threshold detector). If the signals from these detectors significantly different, the event is labeled as faulty and signal is not processed (the electronic collimation of the diode).
- Filtration eliminates the overly wide pulses and Pile-Up effect.





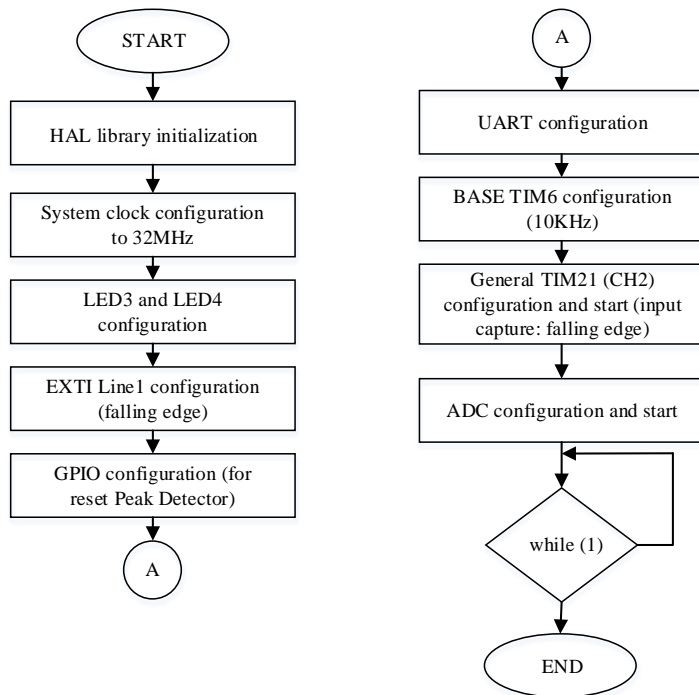
# Processor ARM Cortex M0+ (STM32L053 Discovery board)



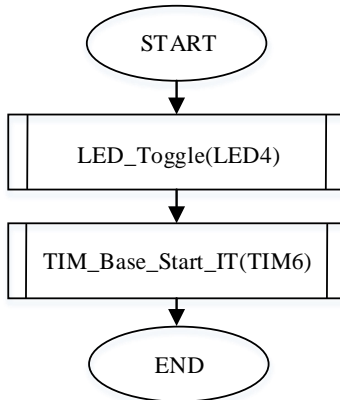


- a) Collection events from peak detector in microprocessor and calculating energy deposition (read ADC measurements and reset peak detector)
- b) Collection events from time over threshold detector and calculating energy deposition (read TTL signal by timer)
- c) Comparison of both methods (both methods work in one processor)
- d) Detection and filtering faulty signals (by comparing values from both detectors)
- e) Detector calibration (photons from  $^{60}\text{Co}$  or  $\alpha$ -particles – Department of radiation dosimetry, protons – Tandetron lab)
- f) Detector test (photons and electrons – Microtron lab)

# My first results (1)



Program: Main()

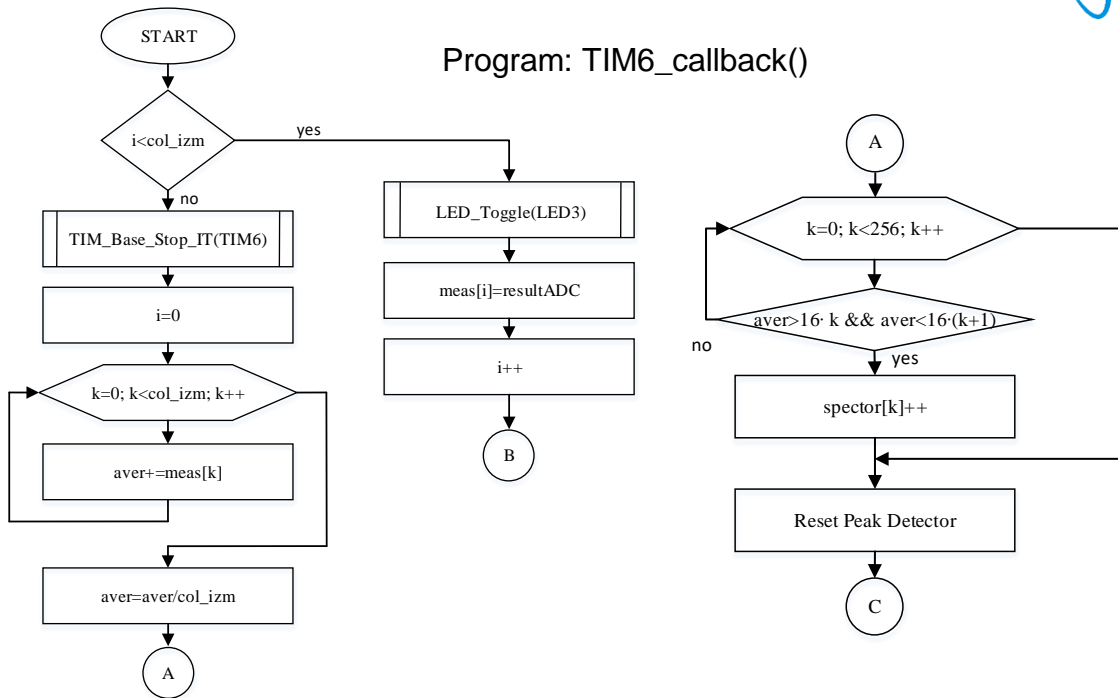


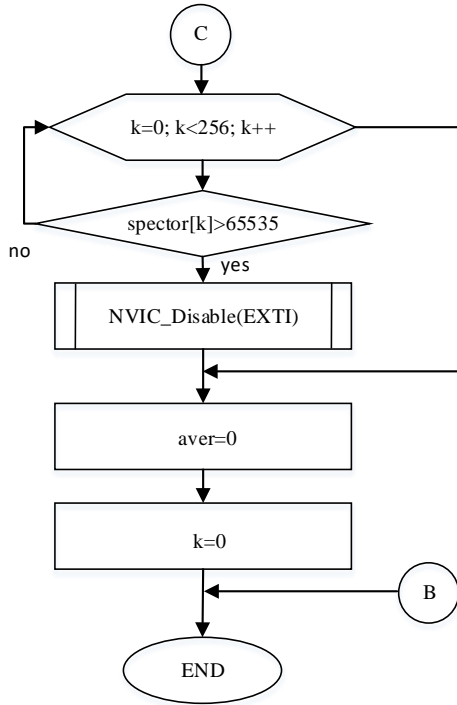
Program: EXTI\_callback()

# My first results (3)



Program: TIM6\_callback()





Continuation of the program:  
TIM6\_callback()



## Progress (from 9 to 25 Feb.):

- ✓ I visited microtron MT25
- ✓ I completed the STM32L0 training in Prague
- ✓ I programmed the first measurement method (for a peak detector)

## Next steps:

- To program the second measurement method (for a time over threshold detector)
- To compare both methods
- To realize detection and filtering faulty signals
- To calibrate detector and make first experiment in Microtron laboratory

## Certificate of accomplishment



This is to certify that  
**Kseniia Larina**  
has successfully completed the  
**STM32L0 training**

*Szymon Panecki*

Instructors  
**S.Panecki**

*A. Barata*

**A.Barata**

Between 2017-02-22 and 2017-02-23  
ST Prague

